MOSFETs Silicon P-Channel MOS (U-MOSVI)

TPCC8106

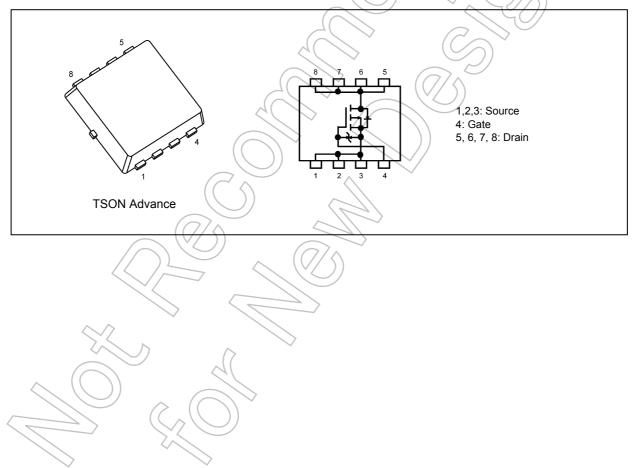
1. Applications

- Motor Drivers
- DC-DC Converters
- Switching Voltage Regulators

2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 9.5 \text{ m}\Omega$ (typ.) ($V_{GS} = -10 \text{ V}$)
- (4) Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -40 \ V)$
- (5) Enhancement mode: $V_{th} = -2.0$ to -3.0 V ($V_{DS} = -10$ V, $I_D = -1.0$ mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25°C unless otherwise specified)

Characteristics				Rating	Unit
Drain-source voltage			V _{DSS}	-40	V
Gate-source voltage			V _{GSS}	-20/+10	
Drain current (DC)		(Note 1)	I _D	-30	A
Drain current (pulsed)		(Note 1)	I _{DP}	-90	
Power dissipation	(T _c = 25°C)		PD	46.8	W
Power dissipation	(t = 10 s)	(Note 2)	PD	2.27	W
Power dissipation	(t = 10 s)	(Note 3)	Pp 7	0.84	W
Single-pulse avalanche energy		(Note 4)	EAS	78.9	mJ
Single-pulse avalanche current			HAS	-30	A
Channel temperature		(Note 5)		175	°C
Storage temperature		G	T _{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

C	naracteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	(T _c = 25°C)	R _{th(ch-c)}	3.2	°C/W
Channel-to-ambient thermal resistance	(t = 10 s) (Not	e 2) R _{th(ch-a)}	66	°C/W
Channel-to-ambient thermal resistance	(t = 10 s) (Not	e 3) R _{th(ch-a)}	178	°C/W

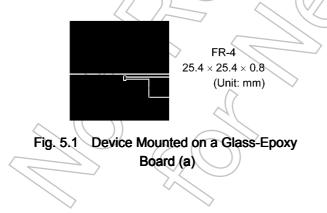
Note 1: Ensure that the channel temperature does not exceed 175°C.

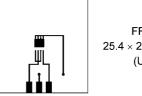
Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = -25 V, T_{ch} = 25°C (initial), L = 91 µH, R_G = 25 Ω , I_{AS} = -30 A

Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.





FR-4 25.4 × 25.4 × 0.8 (Unit: mm)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V _{GS} = -16/+10 V, V _{DS} = 0 V	_	_	±10	μA
Drain cut-off current	I _{DSS}	V _{DS} = -40 V, V _{GS} = 0 V	X	_	-10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = -10 mA, V _{GS} = 0 V	-40	-	_	V
Drain-source breakdown voltage (Note 6)	V _{(BR)DSX}	I _D = -10 mA, V _{GS} = 10 V	-30)2	_	
Gate threshold voltage	V _{th}	V _{DS} = -10 V, I _D = -1.0 mA	-2.0	/_	-3.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = -6 V, I _D = -15 A	()	11.8	18.9	mΩ
		V _{GS} = -10 V, I _D = -15 A)	9.5	12.3	

Note 6: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	X	3100)) —	pF
Reverse transfer capacitance	C _{rss}		\sim	320	—	
Output capacitance	C _{oss}			390	_	
Switching time (rise time)	tr	See Figure 6.2.1.		7	—	ns
Switching time (turn-on time)	t _{on}		<u> </u>	16	_	
Switching time (fall time)	t _f		<i>D</i> –	55	_	
Switching time (turn-off time)	t _{off}		_	209	_	

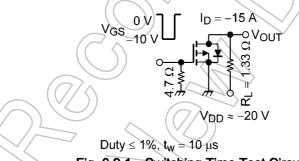


Fig. 6.2.1 Switching Time Test Circuit

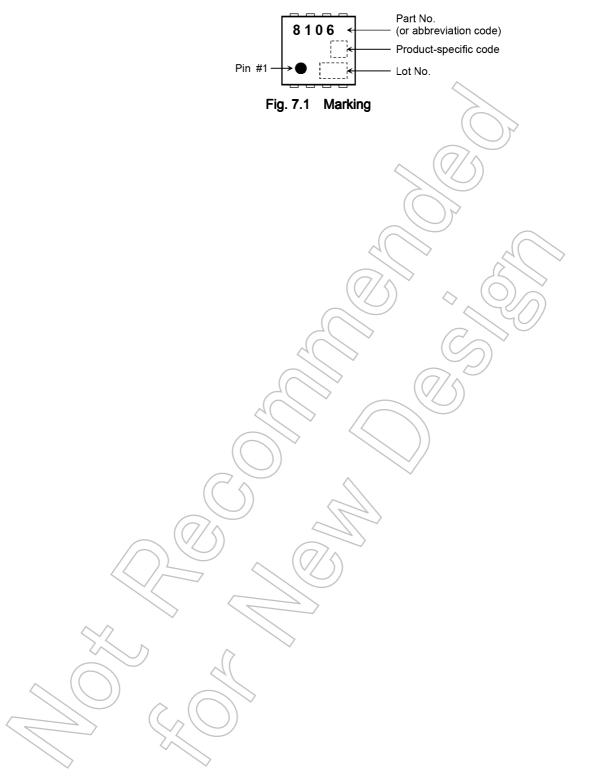
6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx$ -32 V, V_{GS} = -10 V, I_D = -30 A	_	66	_	nC
Gate-source charge 1	Q _{gs1}			10	_	
Gate-drain charge	Q _{gd}		_	19		

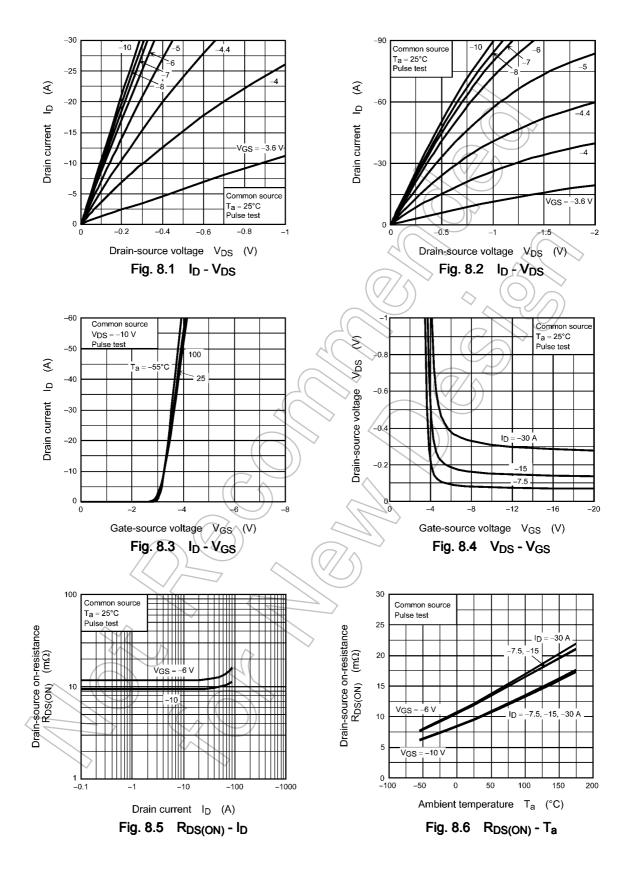
6.4. Source-Drain Characteristics (Ta = 25°C unless otherwise specified)

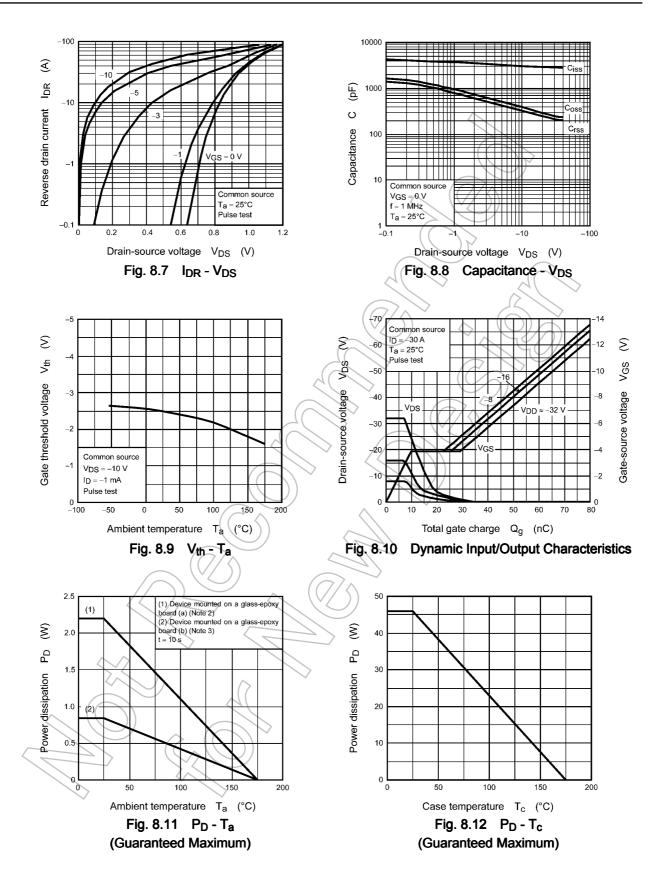
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (N	Note 1)	I _{DRP}	—			-90	Α
Diode forward voltage		V _{DSF}	I _{DR} = -30 A, V _{GS} = 0 V	_	_	1.2	V

7. Marking

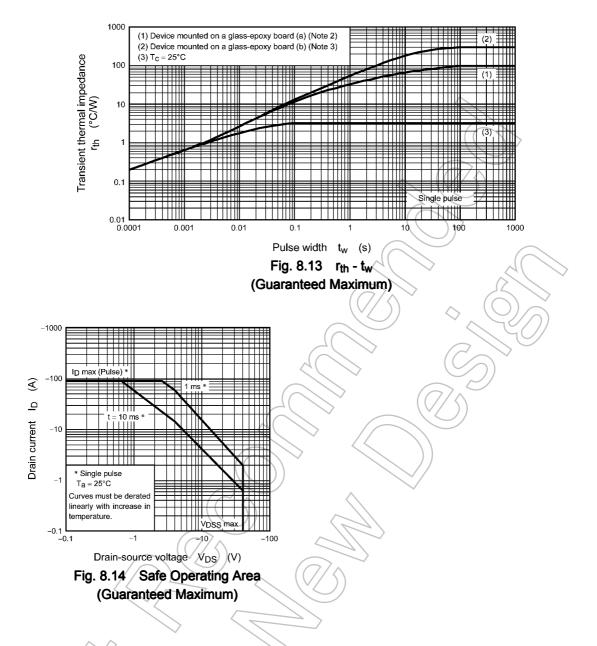


8. Characteristics Curves (Note)







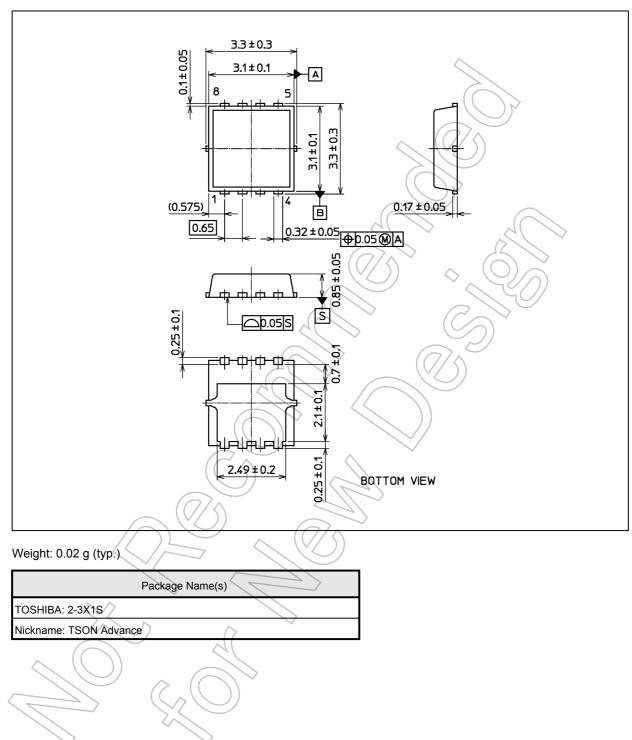


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

TPCC8106

Unit: mm



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